



PATENT
97-CCP-251 DIV

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)
ERIC GERRITSEN, et al.)
Serial No.: 09/858,400)
Filed: May 16, 2001)
For: PROCESS FOR FORMING A)
LOW-RESISTIVITY TITANIUM)
SILICIDE LAYER ON A SILICON)
SEMICONDUCTOR SUBSTRATE)
AND THE RESULTING DEVICE)

Group Art Unit: 2813

Examiner: T. Nguyen

*#3/Election
AND
10/24/02*

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ELECTION

Commissioner for Patents
Washington, D.C. 20231

Sir:

In response to the Office Action dated September 23, 2002, in connection with the above-identified application, please enter and consider the following remarks.

I hereby certify that this correspondence
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Stephen Bongini
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SB 10/15/02
Signature Dated